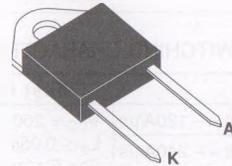


**FAST RECOVERY RECTIFIER DIODE**

- VERY HIGH REVERSE VOLTAGE CAPABILITY
- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING
- INSULATED : Capacitance 15pF

 Insulating voltage 2500 V<sub>RMS</sub>

**Isolated  
DOP3I  
(Plastic)**
**SUITABLE APPLICATIONS**

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

**ABSOLUTE MAXIMUM RATINGS**

| Symbol                             | Parameter                              | Value                               | Unit |
|------------------------------------|--|-------------------------------------|------|
| V <sub>RRM</sub>                   | Repetitive Peak Reverse Voltage        | 1000                                | V    |
| V <sub>RSM</sub>                   | Non Repetitive Peak Reverse Voltage    | 1000                                | V    |
| I <sub>FRM</sub>                   | Repetitive Peak Forward Current        | t <sub>p</sub> ≤ 10μs               | A    |
| I <sub>F(RMS)</sub>                | RMS Forward Current                    | 70                                  | A    |
| I <sub>F(AV)</sub>                 | Average Forward Current                | T <sub>case</sub> = 50°C<br>δ = 0.5 | A    |
| I <sub>FSM</sub>                   | Surge Non Repetitive Forward Current   | t <sub>p</sub> = 10ms<br>Sinusoidal | A    |
| P                                  | Power Dissipation                      | T <sub>case</sub> = 50°C            | W    |
| T <sub>stg</sub><br>T <sub>j</sub> | Storage and Junction Temperature Range | - 40 to + 150                       | °C   |

**THERMAL RESISTANCE**

| Symbol               | Parameter     | Value | Unit |
|----------------------|---------------|-------|------|
| R <sub>th(j-c)</sub> | Junction-case | 1.6   | °C/W |

**ELECTRICAL CHARACTERISTICS**

**STATIC CHARACTERISTICS**

| Symbol | Test Conditions           |                    | Min. | Typ. | Max. | Unit          |
|--------|---------------------------|--------------------|------|------|------|---------------|
| $I_R$  | $T_j = 25^\circ\text{C}$  | $V_R = V_{RRM}$    |      |      | 100  | $\mu\text{A}$ |
|        | $T_j = 100^\circ\text{C}$ |                    |      |      | 5    | $\text{mA}$   |
| $V_F$  | $T_j = 25^\circ\text{C}$  | $I_F = 30\text{A}$ |      |      | 1.9  | V             |
|        | $T_j = 100^\circ\text{C}$ |                    |      |      | 1.8  |               |

**RECOVERY CHARACTERISTICS**

| Symbol   | Test Conditions          |                     |                                     | Min.                    | Typ. | Max. | Unit |
|----------|--------------------------|---------------------|-------------------------------------|-------------------------|------|------|------|
| $t_{rr}$ | $T_j = 25^\circ\text{C}$ | $I_F = 1\text{A}$   | $di_F/dt = -15\text{A}/\mu\text{s}$ | $V_R = 30\text{V}$      |      | 165  | ns   |
|          |                          | $I_F = 0.5\text{A}$ | $I_R = 1\text{A}$                   | $I_{rr} = 0.25\text{A}$ |      | 70   |      |

**TURN-OFF SWITCHING CHARACTERISTICS**

| Symbol    | Test Conditions                      |  | Min. | Typ. | Max. | Unit |
|-----------|--------------------------------------|--|------|------|------|------|
| $t_{IRM}$ | $di_F/dt = -120\text{A}/\mu\text{s}$ | $V_{CC} = 200\text{V}$ $I_F = 30\text{A}$<br>$L_p \leq 0.05\mu\text{H}$ $T_j = 100^\circ\text{C}$<br>See Figure 11 |      |      | 200  | ns   |
|           | $di_F/dt = -240\text{A}/\mu\text{s}$ |  |      | 120  |      |      |
| $I_{RM}$  | $di_F/dt = -120\text{A}/\mu\text{s}$ |  |      |      | 19.5 | A    |
|           | $di_F/dt = -240\text{A}/\mu\text{s}$ |  |      | 22   |      |      |

**TURN-OFF OVERVOLTAGE COEFFICIENT**

| Symbol                      | Test Conditions  |  | Min. | Typ. | Max. | Unit |
|-----------------------------|--|--|------|------|------|------|
| $C = \frac{V_{RP}}{V_{CC}}$ | $T_j = 100^\circ\text{C}$<br>$di_F/dt = -30\text{A}/\mu\text{s}$ | $V_{CC} = 200\text{V}$ $I_F = I_{F(AV)}$<br>$L_p = 5\mu\text{H}$ See Figure 12 |      |      | 4.5  |      |

To evaluate the conduction losses use the following equations :

$$V_F = 1.47 + 0.010 I_F \qquad P = 1.47 \times I_{F(AV)} + 0.010 I_F^2(\text{RMS})$$

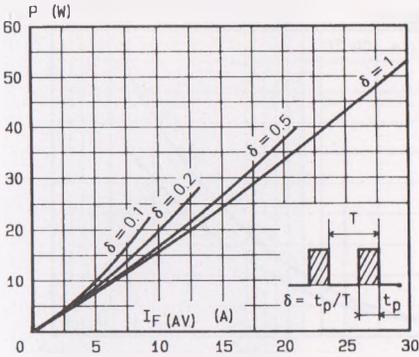


FIGURE 1 : Low frequency power losses versus average current.

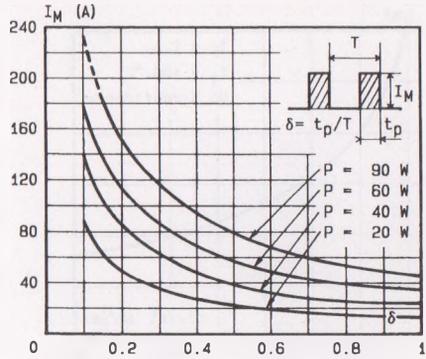


FIGURE 2 : Peak current versus form factor.

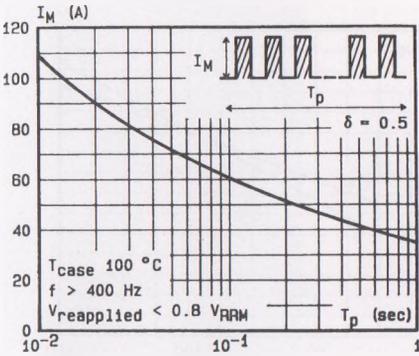


FIGURE 3 : Non repetitive peak surge current versus overload duration.

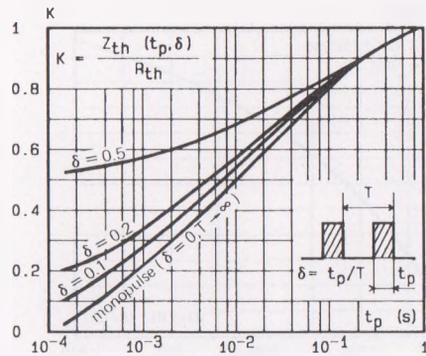


FIGURE 4 : Thermal impedance versus pulse width.

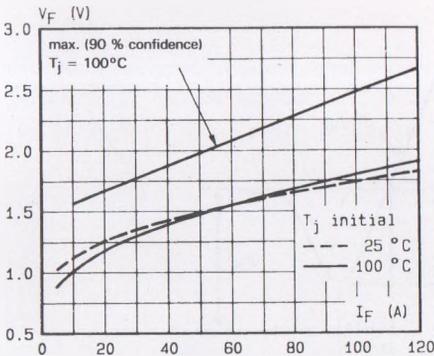


FIGURE 5 : Voltage drop versus forward current.

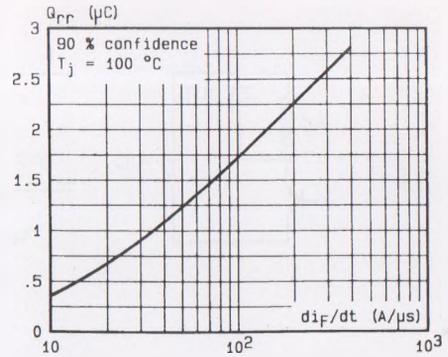


FIGURE 6 : Recovery charge versus  $di_F/dt$ .

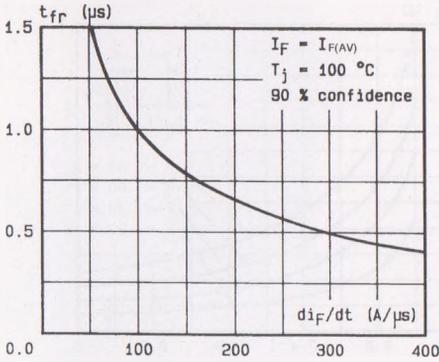


FIGURE 7 : Recovery time versus  $di_F/dt$ .

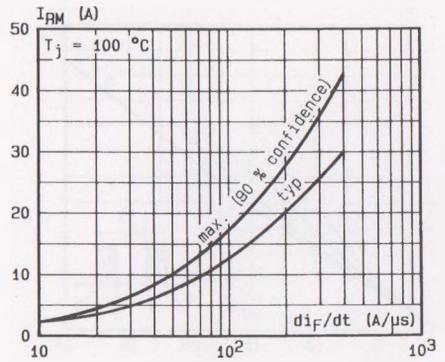


FIGURE 8 : Peak reverse current versus  $di_F/dt$ .

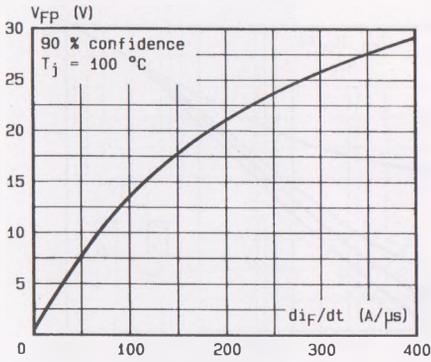


FIGURE 9 : Peak forward voltage versus  $di_F/dt$ .

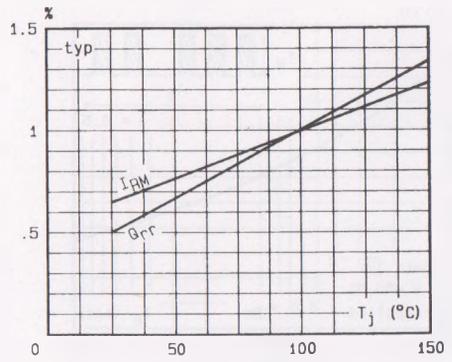


FIGURE 10 : Dynamic parameters versus junction temperature.

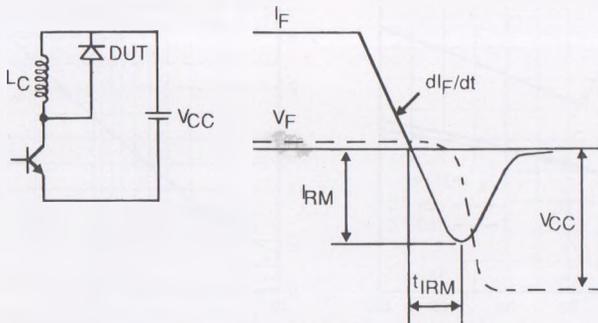


Figure 11 : Turn-off switching characteristics (without series inductance).

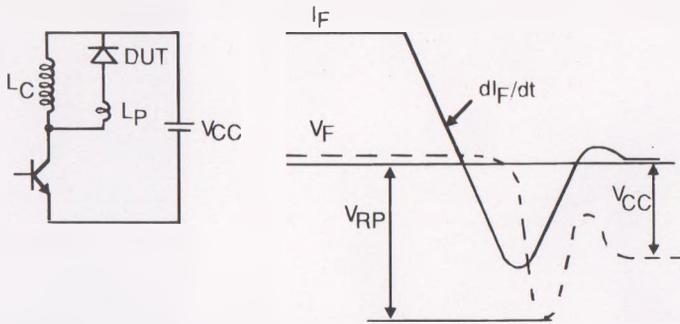


Figure 12 : Turn-off switching characteristics (with series inductance).